

BCR20AM-12LA

Triac

Medium Power Use

REJ03G0299-0300 Rev.3.00 Nov 30, 2007

WWW.DZSG

Features

 $I_{T (RMS)}$: 20 A V_{DRM}: 600 V

 I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 30 mA (20 mA) Note6 WW.DZSG.COM Non-Insulated Type

Planar Passivation Type

Outline

RENESAS Package code: PRSS0004AA-A (Package name: TO-220)





- T₁ Terminal
- 2. T₂ Terminal
- 3. Gate Terminal
- 4. T₂ Terminal

Applications

Vacuum cleaner, electric heater, light dimmer, copying machine, and controller for other motor and heater

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Faranietei	Symbol	12		
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V	
Non-repetitive peak off-state voltage Note1	V_{DSM}	720	V	



BCR20AM-12LA

Parameter	Symbo	Ratings	Unit	Conditions	
	I				
RMS on-state current	I _{T (RMS)}	20	А	Commercial frequency, sine full wave 360° conduction, Tc = 109°C ^{Note3}	
Surge on-state current	I _{TSM}	200	А	60Hz sinewave 1 full cycle, peak value, non-repetitive	
I ² t for fusing	l ² t	167	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	
Peak gate power dissipation	P _{GM}	5	W		
Average gate power dissipation	P _{G (AV)}	0.5	W		
Peak gate voltage	V_{GM}	10	V		
Peak gate current	I _{GM}	2	Α		
Junction temperature	Tj	- 40 to +125	°C		
Storage temperature	Tstg	- 40 to +125	°C		
Mass	_	2.0	g	Typical value	

Notes: 1. Gate open.

Electrical Characteristics

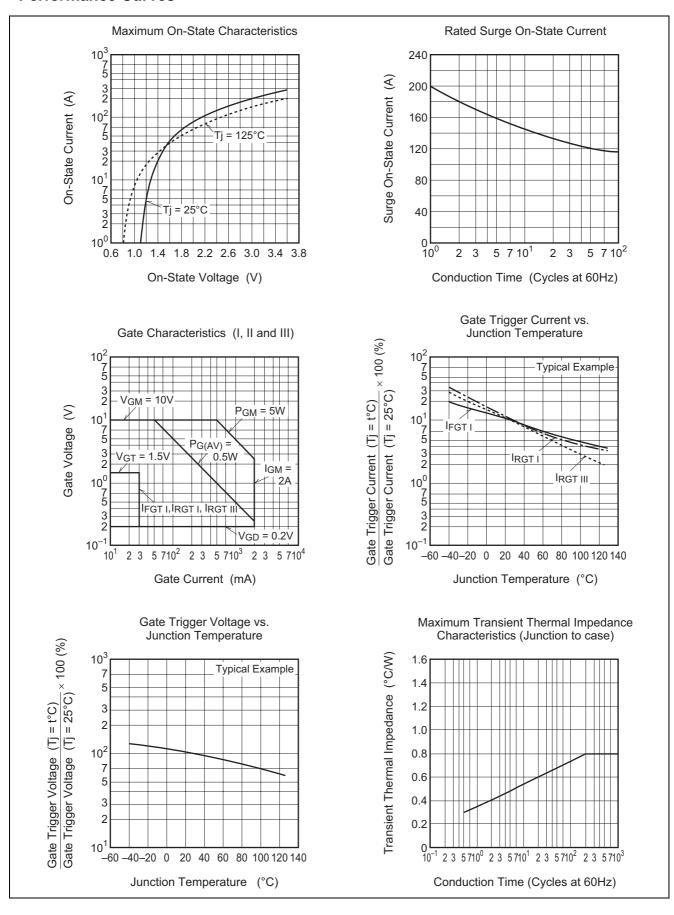
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}	_	_	2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V_{TM}	_	_	1.5	V	Tc = 25°C, I _{TM} = 30 A, Instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}	_	_	1.5	V	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$
	III	V_{RGTIII}	_	_	1.5	V	
Gate trigger current ^{Note2}	I	I _{FGTI}	_	_	30 ^{Note6}	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	I_{RGTI}	_	_	30 ^{Note6}	mA	$R_G = 330 \Omega$
	III	I _{RGTIII}	_	_	30 ^{Note6}	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	_	_	0.8	°C/W	Junction to case Note3 Note4
Critical-rate of rise of off-sta commutating voltage Note5	te	(dv/dt)c	10	_	_	V/μs	Tj = 125°C

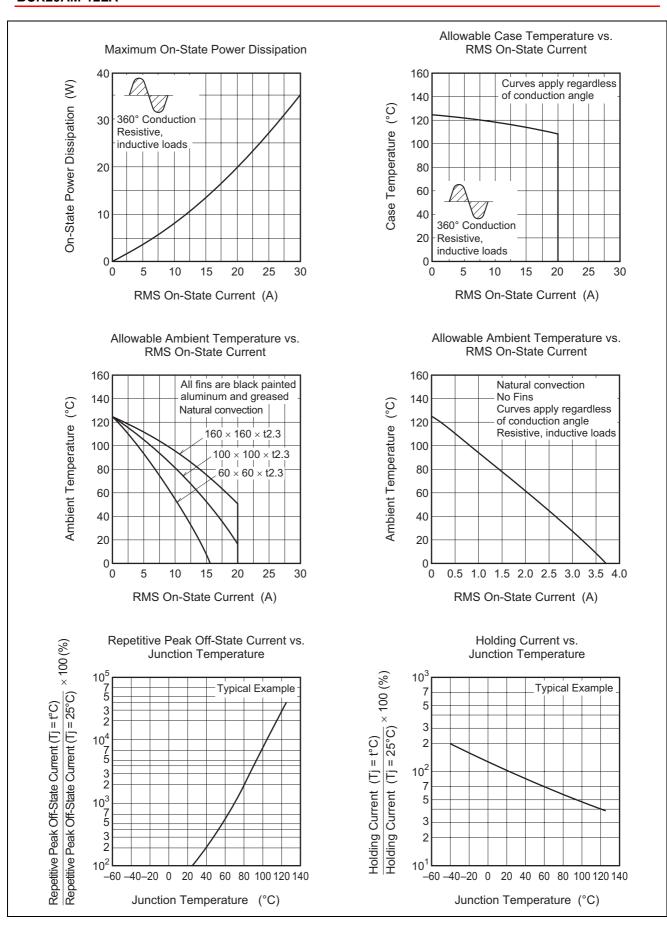
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

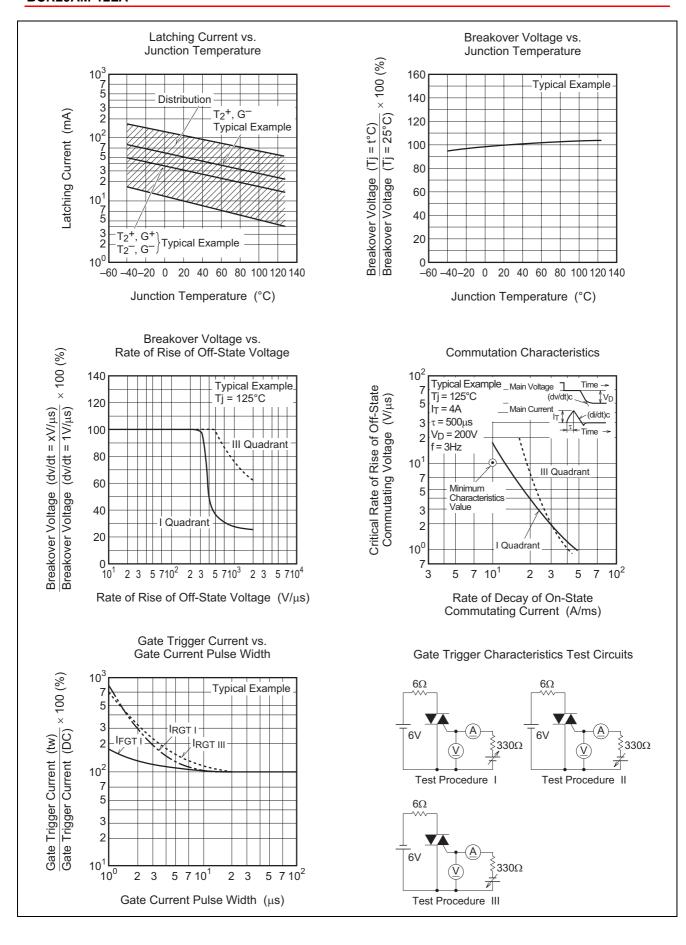
- 3. Case temperature is measured at the T_2 tab 1.5 mm away from the molded case.
- 4. The contact thermal resistance $R_{th\ (c\text{-}f)}$ in case of greasing is 1.0°C/W.
- 5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.
- 6. High sensitivity ($I_{GT} \le 20$ mA) is also available. (I_{GT} item: 1)

Test conditions	Commutating voltage and current waveforms (inductive load)		
1. Junction temperature Tj = 125°C	Supply Voltage		
2. Rate of decay of on-state commutating current (di/dt)c = -10 A/ms	Main Current (di/dt)c → Time		
3. Peak off-state voltage V _D = 400 V	Main Voltage Time		

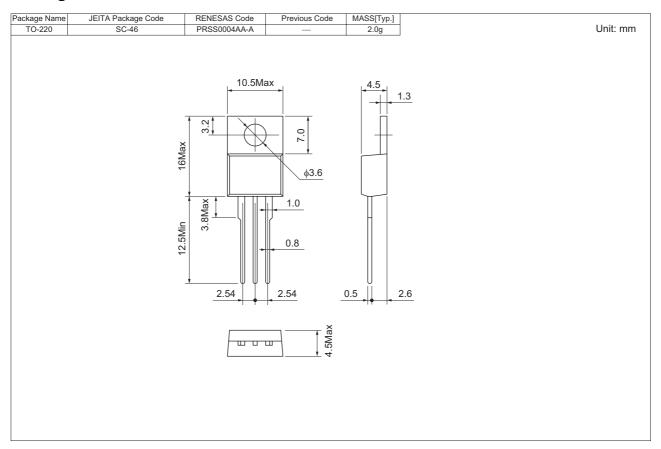
Performance Curves







Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name	BCR20AM-12LA
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	BCR20AM-12LA-A8

Note: Please confirm the specification about the shipping in detail.

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Notes:

 1. This document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas products for their use. Renesas neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of Renesas or any third party with respect to the information in this document.

 2. Renesas shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.

 3. You should not use the products or the technology described in this document in this document property or other rights arising out of the use of any information in this document of the purpose of military applications such as the development of weapons of mass destruction or for the purpose of any other military use. When exporting the products or technology described herein, you should follow the applicable export control laws and regulations, and procedures required by such laws and regulations.

 4. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information with a Renesas sales office. Also, please pay regular and careful attention to additional and different information included in this document.

 4. All information included in this document with a Renesas sales office. Also, please pay regular and careful attention to additional and different information in be disclosed by Renesas such as that disclosed through our website. (http://www.renesas.com)

 5. Renesas has used reasonable care in compiling the information included in this document, but Renesas assumes no liability whatsoever for any damages incurred as a result of errors or omissions in

- undersea communication transmission. If you are considering the use of our products for such purposes, please contact a Renesa's sales office beforehand. Renesa's sha have no liability for damages arising out of the uses set forth above.

 8. Notwithstanding the preceding paragraph, you should not use Renesas products for the purposes listed below:

 (1) artificial life support devices or systems

 (2) surgical implantations

 (3) healthcare intervention (e.g., excision, administration of medication, etc.)

 (4) any other purposes that pose a direct threat to human life

 Renesas shall have no liability for damages arising out of the uses set forth in the above and purchasers who elect to use Renesas products in any of the foregoing applications shall indermity and hold harmless Renesas Technology Corp., its affiliated companies and their officers, directors, and employees against any and all damages arising out of such applications.

 9. You should use the products described herein within the range specified by Renesas, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas shall have no liability for malfunctions or damages arising out of the use of Renesas products beyond such specified ranges.

 10. Although Renesas endeavors to improve the quality and reliability of its products, lice products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is ve



RENESAS SALES OFFICES

http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd.10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510